



TRIACS

- GLASS PASSIVATED CHIP
- I_{GT} SPECIFIED IN FOUR QUADRANTS

ADVANTAGES

- EXCELLENT $(dv/dt)_C : > 10 \text{ V}/\mu\text{s}$
- METALLIC ENCAPSULATION GIVES AN EXCELLENT THERMAL IMPEDANCE AND HIGH RELIABILITY CONSTRUCTION

APPLICATIONS

- MOTOR CONTROL
- HEATING CONTROL
- LIGHT DIMMER

DESCRIPTION

Power triacs suited for use on 220 V and 380 V main.

Thread : 1/4" -28 UNF : type N°
M6 on request : type N° + suffix M



TO 48
(Metal)

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state Current (360° conduction angle)	$T_C = 60^\circ\text{C}$	25	A
I_{TSM}	Non Repetitive Surge Peak on-state Current (T_j initial = 25°C - Half sine wave)	$t = 8.3 \text{ ms}$	262	A
		$t = 10 \text{ ms}$	250	
I^2t	I^2t Value for Fusing	$t = 10 \text{ ms}$	312.5	A ² s
di/dt	Critical Rate of Rise of on-state Current (1)	Repetitive $F = 50 \text{ Hz}$	20	A/ μs
		Non Repetitive	100	
T_{slg}	Storage and Operating Junction Temperature Range		- 40 to 150	$^\circ\text{C}$
T_j			- 40 to 100	$^\circ\text{C}$

Symbol	Parameter	TRAL				Unit
		1125D	2225D	3325D	3825D	
V_{DRM}	Repetitive Peak off-state Voltage (2)	200	400	600	700	V

(1) $I_G = 1.5 \text{ A}$ $di/dt = 1 \text{ A}/\mu\text{s}$

(2) $T_j = 100^\circ\text{C}$.

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(c-h)}$	Contact (case-heatsink) for Recommended Stud Torque	0.4	$^\circ\text{C}/\text{W}$
$R_{th(j-c)} \text{ DC}$	Junction to Case for DC	1.24	$^\circ\text{C}/\text{W}$
$R_{th(j-c)} \text{ AC}$	Junction to Case for 360° Conduction Angle ($F = 50 \text{ Hz}$)	0.93	$^\circ\text{C}/\text{W}$

GATE CHARACTERISTICS (maximum values)

$P_{GM} = 40\text{ W}$ ($t_p = 10\text{ }\mu\text{s}$) $I_{GM} = 6\text{ A}$ ($t_p = 10\text{ }\mu\text{s}$)
 $P_{G(AV)} = 1\text{ W}$ $V_{GM} = 16\text{ V}$ ($t_p = 10\text{ }\mu\text{s}$)

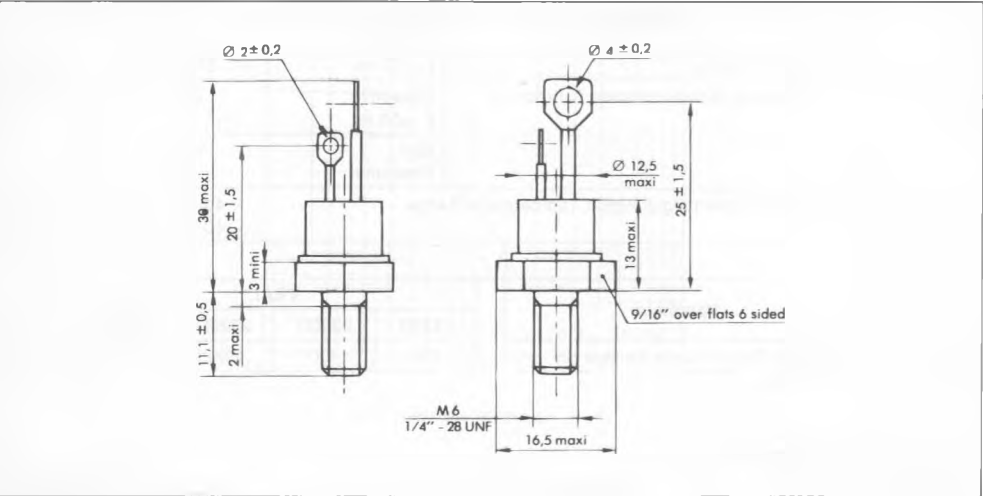
ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions			Quadrants	Min.	Typ.	Max.	Unit
I_{GT}	$T_j = 25\text{ }^\circ\text{C}$ Pulse Duration $> 20\text{ }\mu\text{s}$	$V_D = 12\text{ V}$	$R_L = 33\text{ }\Omega$	I-II-III			100	mA
				IV			150	
V_{GT}	$T_j = 25\text{ }^\circ\text{C}$ Pulse Duration $> 20\text{ }\mu\text{s}$	$V_D = 12\text{ V}$	$R_L = 33\text{ }\Omega$	I-II-III-IV			1.5	V
V_{GD}	$T_j = 100\text{ }^\circ\text{C}$	$V_D = V_{DRM}$	$R_L = 3.3\text{ k}\Omega$	I-II-III-IV	0.2			V
I_H^*	$T_j = 25\text{ }^\circ\text{C}$	$I_T = 500\text{ mA}$	Gate Open				100	mA
I_L	$T_j = 25\text{ }^\circ\text{C}$ Pulse Duration $> 20\text{ }\mu\text{s}$	$V_D = 12\text{ V}$	$I_G = 300\text{ mA}$	I-III-IV		50		mA
				II		100		
V_{TM}^*	$T_j = 25\text{ }^\circ\text{C}$	$I_{TM} = 35\text{ A}$	$t_p = 10\text{ ms}$				2	V
I_{DRM}^*	$T_j = 100\text{ }^\circ\text{C}$	V_{DRM} Specified					3	mA
dv/dt^*	$T_j = 100\text{ }^\circ\text{C}$	Gate Open Linear Slope up to $V_D = 67\% V_{DRM}$			250			V/ μs
$(dv/dt)_c^*$	$T_C = 60\text{ }^\circ\text{C}$ $(di/dt)_c = 11.2\text{ A/ms}$	$V_D = V_{DRM}$	$I_T = 35\text{ A}$		10			V/ μs
t_{gl}	$T_j = 25\text{ }^\circ\text{C}$ $I_G = 200\text{ mA}$	$V_D = V_{DRM}$ $di_G/dt = 2\text{ A}/\mu\text{s}$	$I_T = 35\text{ A}$	I-II-III-IV		3		μs

* For either polarity of electrode A_2 voltage with reference to electrode A_1 .

PACKAGE MECHANICAL DATA

TO 48 Metal



Cooling method : by conduction (method C)
Marking : type number
Weight : $13.5 \pm 1\text{ g}$
Polarity : anode to case
Stud torque : $3.5\text{ mAN min} - 3.8\text{ mAN max}$.

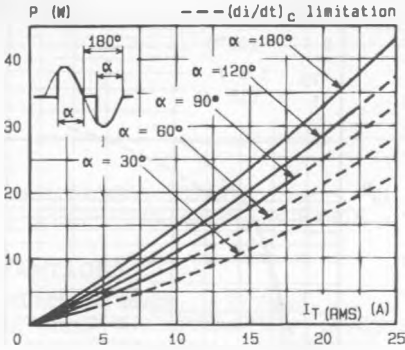


Fig. 1 - Maximum mean power dissipation versus RMS on-state current ($F = 80$ Hz).

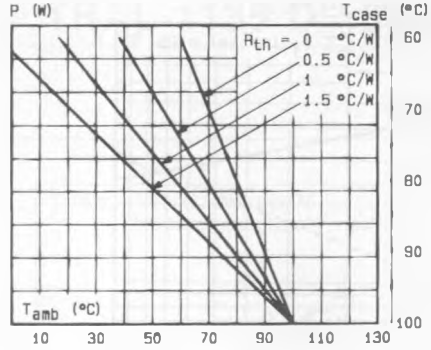


Fig. 2 - Correlation between maximum mean power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact.

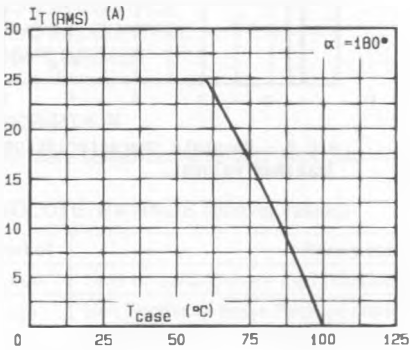


Fig. 3 - RMS on-state current versus case temperature.

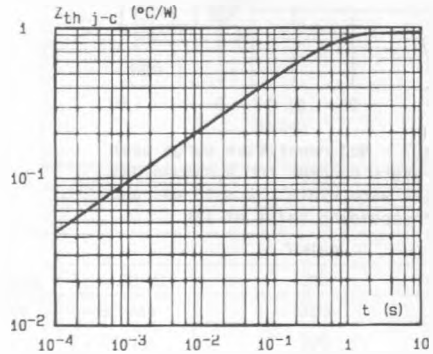


Fig. 4 - Thermal transient impedance junction to case versus pulse duration.

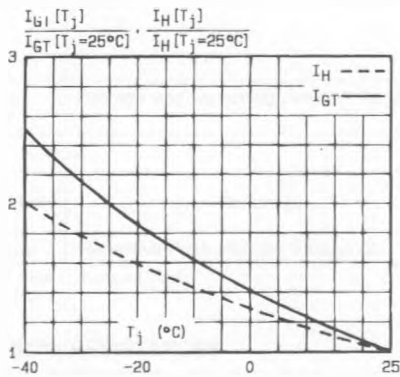


Fig. 5 - Relative variation of gate trigger current and holding current versus junction temperature.

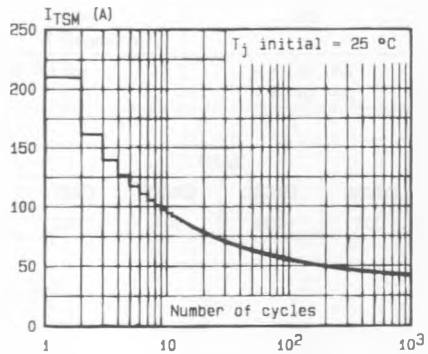


Fig. 6 - Non repetitive surge peak on-state current versus number of cycles.

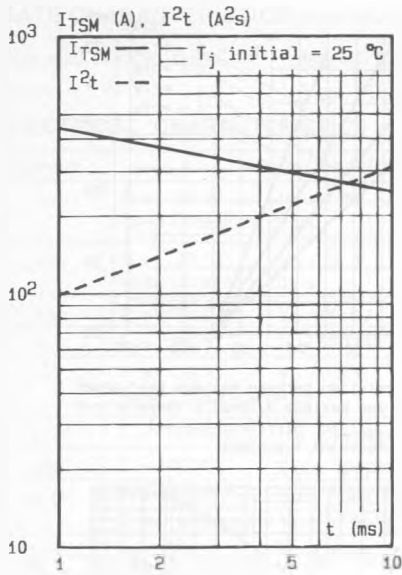


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10$ ms. and corresponding value of I^2t .

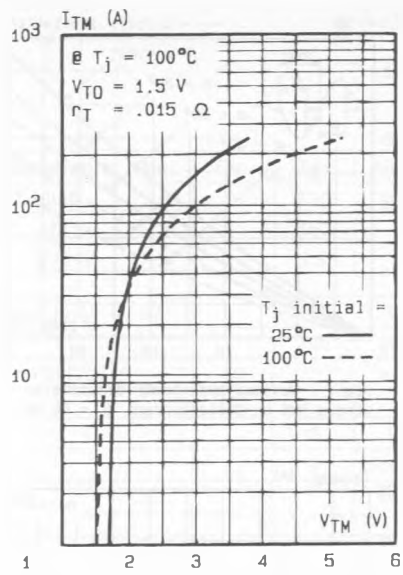


Fig.8 - On-state characteristics (maximum values).